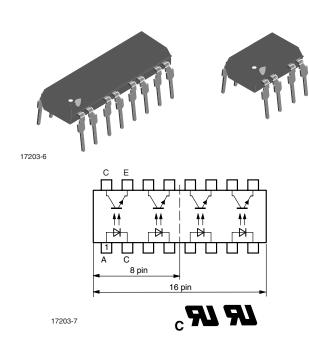


### Vishay Semiconductors

## **Optocoupler, Phototransistor Output**



#### **FEATURES**

- DC isolation test voltage 5000 V<sub>RMS</sub>
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC





#### **APPLICATIONS**

- Programmable logic controllers
- Modems
- · Answering machines
- · General applications

#### **AGENCY APPROVALS**

- UL1577, file no. E57244 system code H, double protection
- cUL tested to CSA 22.2 bulletin 5A, UL1577, file no. E52744

#### **DESCRIPTION**

In the K827PH, K847PH parts each channel consist of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 8 pin (dual); 16 pin (quad) plastic dual inline package.

ORDER INFORMATION				
PART	REMARKS			
K827PH	CTR 50 % to 600 %, DIP-8			
K847PH	CTR 50 % to 600 %, DIP-16			

#### Note

K827PH and K847PH are marked as K827P and K847P respectively.

<b>ABSOLUTE MAXIMUM RATINGS <sup>(1)</sup></b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	TEST CONDITION SYMBOL		UNIT		
INPUT						
Reverse voltage		$V_R$	6	V		
Forward current		I <sub>F</sub>	60	mA		
Forward surge current	t <sub>P</sub> ≤ 10 μs	I <sub>FSM</sub>	1.5	А		
Power dissipation		P <sub>diss</sub>	100	mW		
Junction temperature		Tj	125	°C		
OUTPUT	·					
Collector emitter voltage		V <sub>CEO</sub>	70	V		
Emitter collector voltage		V <sub>ECO</sub>	7	V		
Collector current		I <sub>C</sub>	50	mA		
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I <sub>CM</sub>	100	mA		
Power dissipation		P <sub>diss</sub>	150	mW		
Junction temperature		Tj	125	°C		

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# Vishay Semiconductors Optocoupler, Phototransistor Output



<b>ABSOLUTE MAXIMUM RATINGS</b> (1) (T <sub>amb</sub> = 25 °C, unless otherwise specified)									
PARAMETER TEST CONDITION SYMBOL VALUE UNIT									
COUPLER									
AC isolation test voltage (RMS)	t = 1 min	V <sub>ISO</sub>	5000	$V_{RMS}$					
Total power dissipation		P <sub>tot</sub>	250	mW					
Operating ambient temperature range		T <sub>amb</sub>	- 40 to + 100	°C					
Storage temperature range		T <sub>stg</sub>	- 55 to + 125	°C					
Soldering temperature (2)	2 mm from case, $t \le 10 \text{ s}$	T <sub>sld</sub>	260	°C					

#### **Notes**

<sup>(2)</sup> Refer to wave profile for soldering conditions for through hole devices.

<b>ELECTRICAL CHARACTERISTICS</b> (1) (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT								
Forward voltage	I <sub>F</sub> = 50 mA	$V_{F}$		1.25	1.6	V		
Junction capacitance	$V_R = 0 V$ , $f = 1 MHz$	C <sub>j</sub>		50		pF		
OUTPUT								
Collector emitter voltage	I <sub>C</sub> = 100 μA	$V_{CEO}$	70			V		
Emitter collector voltage	I <sub>E</sub> = 100 μA	V <sub>ECO</sub>	7			V		
Collector dark current	$V_{CE} = 20 \text{ V}, I_F = 0, E = 0$	I <sub>CEO</sub>			100	nA		
COUPLER								
Collector emitter saturation voltage	I <sub>F</sub> = 10 mA, I <sub>C</sub> = 1 mA	V <sub>CEsat</sub>			0.3	V		
Cut-off frequency	$I_F$ = 10 mA, $V_{CE}$ = 5 V, $R_L$ = 100 $\Omega$	f <sub>c</sub>		100		kHz		
Coupling capacitance	f = 1 MHz	C <sub>k</sub>		0.3		pF		

#### Note

<sup>(1)</sup> Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
$I_{C}/I_{F}$ $V_{CE} = 5 \text{ V}, I_{F} = 5 \text{ mA}$	K827PH	CTR	50		600	%	
	V <sub>CE</sub> = 5 V, I <sub>F</sub> = 5 IIIA	K847PH	CTR	50		600	%

www.vishay.com 544 For technical questions, contact: optocoupleranswers@vishay.com

<sup>(1)</sup> Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.



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SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Delay time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 1)	t <sub>d</sub>		3		μs
Rise time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 1)	t <sub>r</sub>		3		μs
Fall time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 1)	t <sub>f</sub>		4.7		μs
Storage time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 1)	t <sub>s</sub>		0.3		μs
Turn-on time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 1)	t <sub>on</sub>		6		μs
Turn-off time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 1)	t <sub>off</sub>		5		μs
Turn-on time	$V_S$ = 5 V, $I_F$ = 10 mA, $R_L$ = 1 k $\Omega$ (see figure 2)	t <sub>on</sub>		9		μs
Turn-off time	$V_S$ = 5 V, $I_F$ = 10 mA, $R_L$ = 1 k $\Omega$ (see figure 2)	t <sub>off</sub>		18		μs

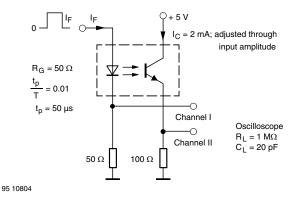


Fig. 1 - Test Circuit, Non-Saturated Operation

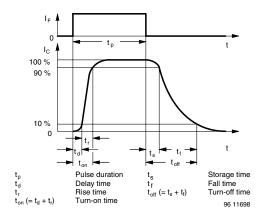


Fig. 3 - Switching Times

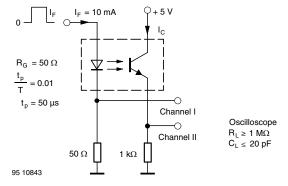


Fig. 2 - Test Circuit, Saturated Operation

### Vishay Semiconductors Optocoupler, Phototransistor Output



### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

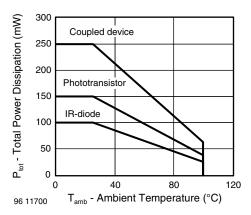
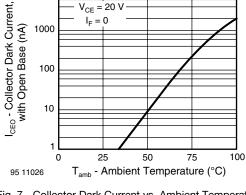


Fig. 4 - Total Power Dissipation vs. Ambient Temperature



10 000

Fig. 7 - Collector Dark Current vs. Ambient Temperature

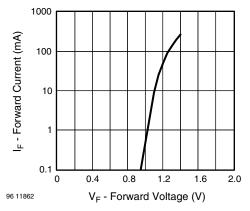


Fig. 5 - Forward Current vs. Forward Voltage

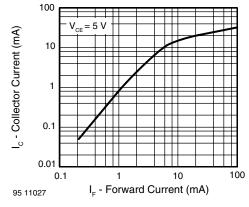


Fig. 8 - Collector Current vs. Forward Current

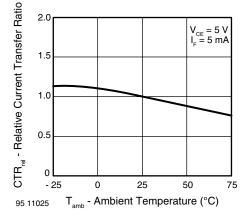


Fig. 6 - Relative Current Transfer Ratio vs. Ambient Temperature

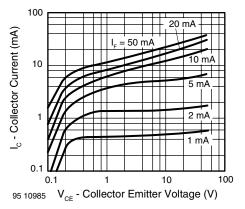


Fig. 9 - Collector Current vs. Collector Emitter Voltage



# Optocoupler, Phototransistor Output Vishay Semiconductors

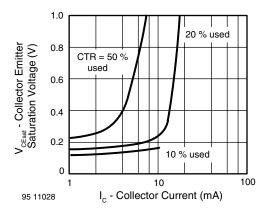


Fig. 10 - Collector Emitter Saturation Voltage vs. Collector Current

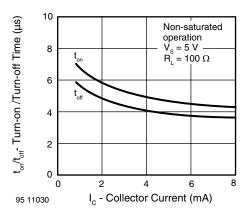


Fig. 13 - Turn-on/off Time vs. Collector Current

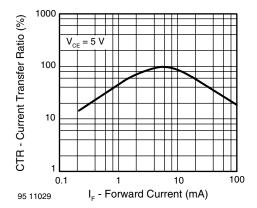


Fig. 11 - Current Transfer Ratio vs. Forward Current

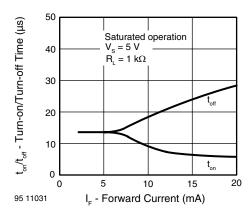
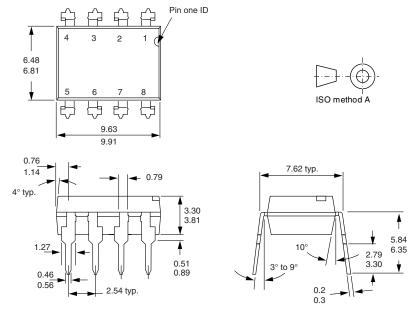


Fig. 12 - Turn-on/Turn-off Time vs. Forward Current

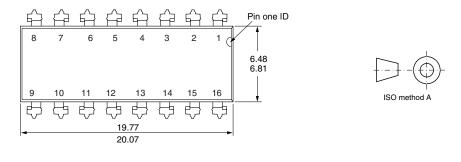
## Vishay Semiconductors Optocoupler, Phototransistor Output

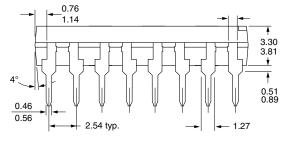


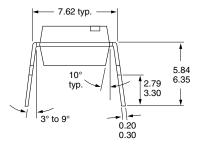
### **PACKAGE DIMENSIONS** in millimeters



i178006







i178007

#### **PACKAGE MARKING**





Vishay

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